



DMG2301U

P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	l _D max T _A = +25°C
<u> </u>	80mΩ @ V _{GS} = 4.5V	-2.7A
-20V	110mΩ @ V _{GS} = 2.5V	-2.1A

Description

This MOSFET has been designed to minimize the on-state resistance (R_{DS(on)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Backlighting
- **Power Management Functions**
- **DC-DC Converters**
- Motor control

Features

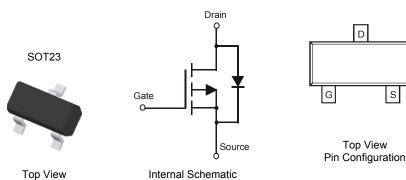
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 @3

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- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMG2301U-7	SOT23	3000/Tape & Reel

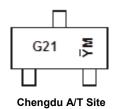
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. Notes:

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information





G21 = Product Type Marking Code YM = Date Code Marking for SAT (Shanghai Assembly/ Test site) YM = Date Code Marking for CAT (Chengdu Assembly/ Test site) Y or \overline{Y} = Year (ex: A = 2013) M = Month (ex: 9 = September)

Date Code Key

Date Code Key												
Year	2009	2010	20	11	2012	2013	2014	2015	5 20	016	2017	2018
Code	W	Х	Ì	Y	Z	А	В	С		D	E	F
				-								
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units	
Drain-Source Voltage		V _{DSS}	-20	V	
Gate-Source Voltage		V _{GSS}	±8	V	
Continuous Drain Current (Note 5) V_{GS} = -4.5V	Steady State	T _A = +25°C T _A = +70°C	ID	-2.7 -2.1	A
Continuous Drain Current (Note 5) $V_{GS} = -2.5V$ Steady State $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$			ID	-2.1 -1.7	A
Pulsed Drain Current (Note 6)		I _{DM}	-27	А	

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	0.8	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5)	R _{0JA}	157	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

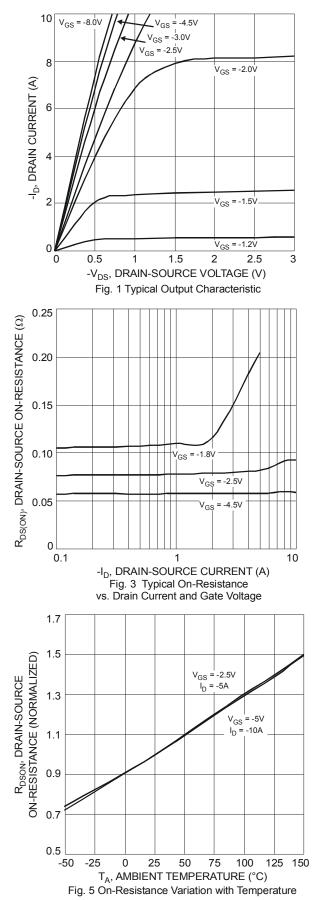
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	-20	_		V	$V_{GS} = 0V, I_D = -250 \mu A$
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	_	_	-1.0	μA	V _{DS} = -16V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	V _{GS} = ±8V, V _{DS} = 0V
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(th)}	-0.45	_	-1.0	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$
Static Drain-Source On-Resistance				80	mΩ	V _{GS} = -4.5V, I _D = -2.8A
	R _{DS (ON)}	_	_	110	mΩ	V _{GS} = -2.5V, I _D = -2.0A
Forward Transfer Admittance	Y _{fs}	_	10		S	V _{DS} = -5V, I _D = -2.8A
Diode Forward Voltage	V _{SD}	_	-0.75	-1.0	V	V _{GS} = 0V, I _S = -1A
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		608		pF	
Output Capacitance	Coss	_	82		pF	−V _{DS} = -6V, V _{GS} = 0V −f = 1.0MHz
Reverse Transfer Capacitance	Crss		72		pF	
Gate Resistance	R _G	_	44.9		Ω	$V_{GS} = 0V, V_{DS} = 0V, f = 1.0MHz$
Total Gate Charge	Qg	_	6.5		nC	
Gate-Source Charge	Qgs	_	0.9		nC	V _{GS} = -4.5V, V _{DS} = -10V, I _D = -3A
Gate-Drain Charge	Q _{qd}	_	1.5		nC	7
Turn-On Delay Time	t _{D(on)}	_	12.5	40	ns	
Turn-On Rise Time	tr	_	10.3	30	ns	V _{DS} = -10V, V _{GS} = -4.5V,
Turn-Off Delay Time	t _{D(off)}		46.5	140	ns	R _L = 10Ω, R _G = 1.0Ω, I _D = -1A
Turn-Off Fall Time	tf		22.2	66	ns	

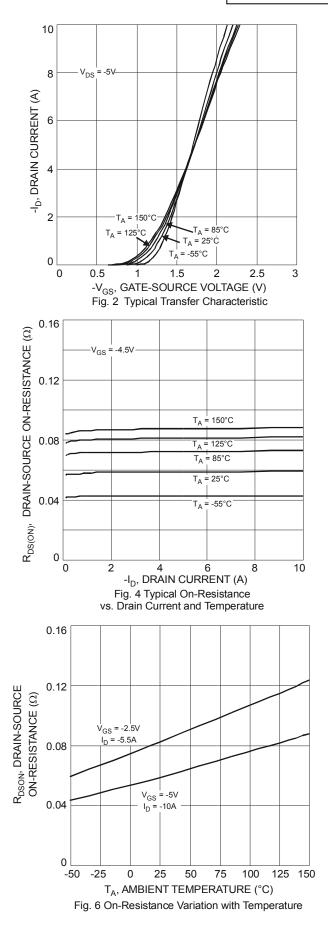
Notes:

Device mounted on FR-4 PCB with minimum recommended pad layout.
Repetitive rating, pulse width limited by junction temperature..
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing.



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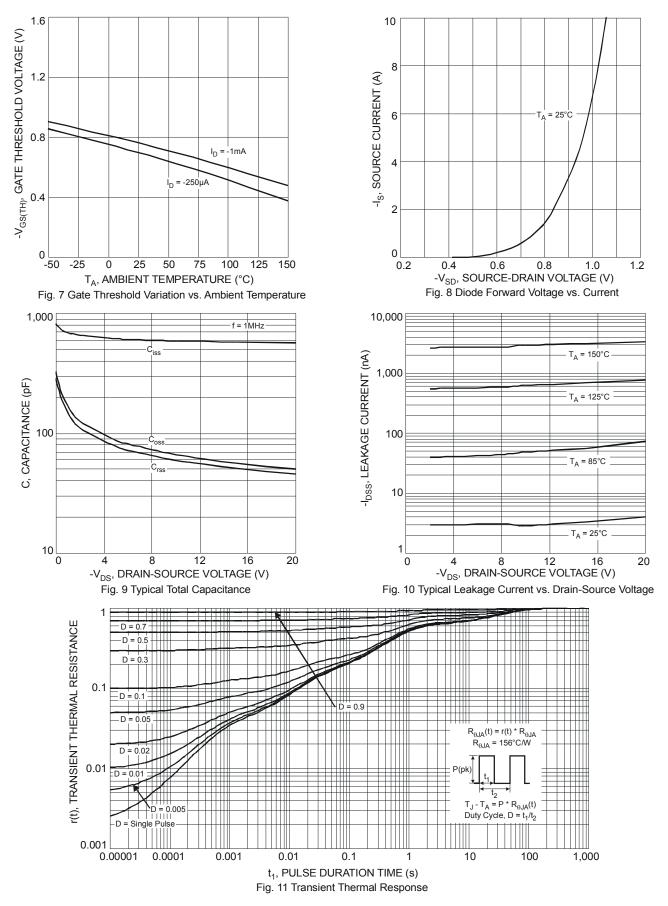




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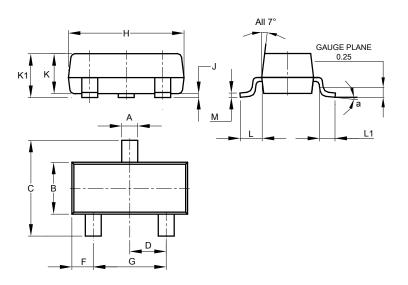
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Package Outline Dimensions

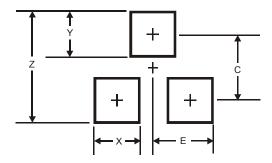
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23								
Dim	Min Max Typ							
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
κ	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
α	8°							
All	Dimens	ions in	mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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